



US/N 10/796,514

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: John P. Snyder et al. Examiner: Su C. Kim
Serial No.: 10/796,514 Conf. No.: 1961 Group Art Unit: 2823
Filed: March 9, 2004 Atty. Dkt. No.: 14467.05
Title: TRANSISTOR HAVING HIGH DIELECTRIC CONSTANT GATE
INSULATING LAYER AND SOURCE AND DRAIN FORMING
SCHOTTKY CONTACT WITH SUBSTRATE

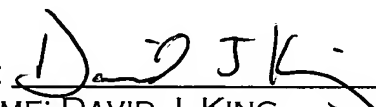
TRANSMITTAL FOR AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- ☒ This Transmittal and a Return Postcard;
- ☒ An Amendment and Response under 37 CFR § 1.111 (20 pages);

SPINNAKER SEMICONDUCTOR, INC
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BY: 
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CERTIFICATE OF MAILING UNDER 37 CFR 1.8: I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Mail Stop Amendment, Commissioner of Patents, P.O. Box 1450, Washington, D.C. 22313-1450, on the 7th day of April, 2008.

By: 
David J King, Reg. No. 53,132